



PATENT  
Customer No. 22,852  
Attorney Docket No. 08038.0027

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Hikaru YOSHITAKA

Serial No.: 09/658,861

Filed: September 8, 2000

For: SEMICONDUCTOR DEVICE AND  
METHOD OF MANUFACTURING  
THE SAME

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) Group Art Unit: 2812  
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) Examiner: Nguyen, H.  
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Assistant Commissioner for Patents  
Washington, DC 20231

Sir:

**AMENDMENT**

In reply to the Office Action dated August 15, 2001, the period for reply having been extended for three months by a request for extension and fee payment filed concurrently herewith, please amend the application as follows:

**IN THE CLAIMS:**

Please cancel claims 1-3 and amend claim 4 as follows:

4. (Amended) A method of manufacturing a semiconductor device, said method comprising the steps of:

forming a wiring layer on a semiconductor substrate having an active region formed thereon;

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